

Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	30	V	
Gate-Source Voltage		V _{GS}	±20		
Continuous Drain Current ^(Note 3)	Tc=25°C		525		
	$T_{\rm C}=100^{\circ}{\rm C}$	l _D	370	А	
Pulsed Drain Current ^(Note 1)	Tc=25°C	I _{DM}	930		
Power Dissipation	Tc=25°C	D	268	W	
	$T_{C}=100^{\circ}C$	PD	134		
Continuous Drain Current ^(Note 4)	T _A =25°C		62	A	
	T _A =70°C	l _D	52		
Power Dissipation	T _A =25 [°] C	Po	3.8	w	
	T _A =70°C		2.6		
Single Pulse Avalanche Current ^(Note 5)		las	32	А	
Single Pulse Avalanche Energy ^(Note 5)		Eas	378	mJ	
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~175	°C	
Thermal Resistance ^(Note 4)	Junction to Case	R _{θJC}	0.56	- °C/W	
	Junction to Ambient	R _{0JA}	40		



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Electrical Characteristics (TA=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	30	-	-	v	
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250uA	1.1	1.6	2.3		
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V, I _D =20A	-	0.51	0.64	mΩ	
		V _{GS} =4.5V, I _D =20A	-	0.74	0.97		
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =30V, V_{GS} =0V	-	-	1	uA	
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V	-	-	±100	nA	
Dynamic ^(Note 6)							
Total Gate Charge	Qg		-	122	160	nC	
Gate-Source Charge	Qgs	V _{DS} =24V, I _D =20A, V _{GS} =10V	-	14.5	-		
Gate-Drain Charge	Q _{gd}	VGS=10V	-	24	-		
Input Capacitance	Ciss		-	7402	9700	pF	
Output Capacitance	Coss	V _{DS} =25V, V _{GS} =0V, f=1MHz	-	2724	3600		
Reverse Transfer Capacitance	Crss	I=IMHZ	-	140	210		
Gate resistance	Rg	f=1MHz	-	3.3	-	Ω	
Turn-On Delay Time	td(on)		-	12	-		
Turn-On Rise Time	tr	V _{DS} =24V, I _D =20A,	-	27	-		
Turn-Off Delay Time	td(off)	$V_{GS}=10V, R_G=3\Omega$	-	129	-	ns	
Turn-Off Fall Time	tf		-	84	-		
Drain-Source Diode							
Diode Forward Current	Is	Tc=25°C	-	-	302		
Pulsed Diode Forward Current	I _{SM}	(Package Limit)	-	-	930	A	
Diode Forward Voltage	V _{SD}	Is=20A, V _{GS} =0V	-	0.73	1.3	V	
Reverse Recovery Time	Trr	$V_{DD}=24V, V_{GS}=0V,$	-	72	-	ns	
Reverse Recovery Charge	Qrr	Is=20A,dIs/dt=100A/us	-	82	-	nC	

NOTES :

- 1. Pulse width100us, Duty cycle<2%.</td>
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Chip capability with an $R_{\theta JC}=0.56^{\circ}C/W$, Pakage limited 120A.
- 4. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 5. E_{AS} is calculated based on the condition of L=1mH, I_{AS}=27.5A, V_{DD}=30V, V_{GS}=10V. 100% test at L=0.5mH, I_{AS}=32A in production.
- 6. Guaranteed by design, not subject to production testing.

SEM CONDUCTOR

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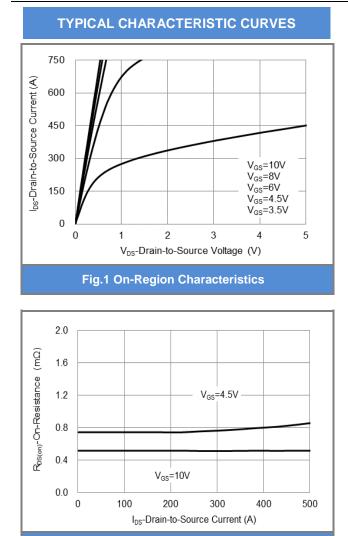
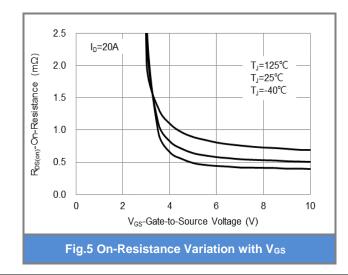


Fig.3 On-Resistance vs. Drain Current



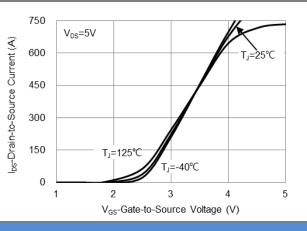


Fig.2 Transfer Characteristics

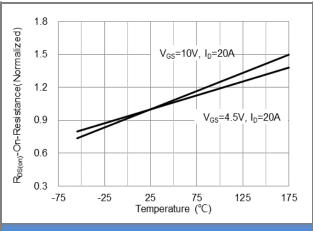
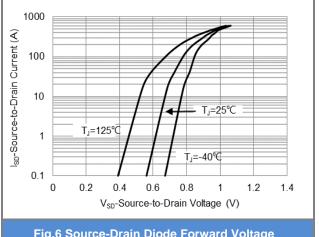


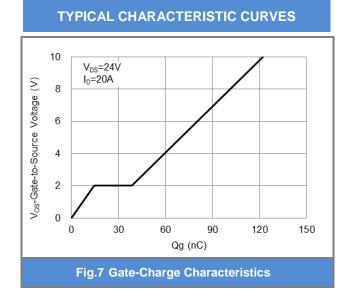
Fig.4 On-Resistance vs. Junction temperature

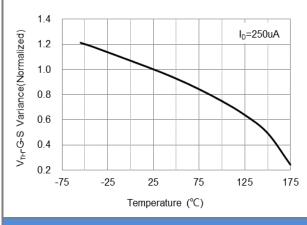


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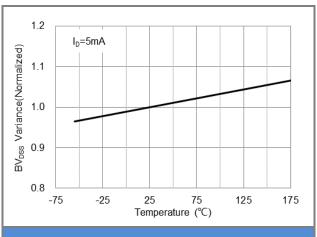
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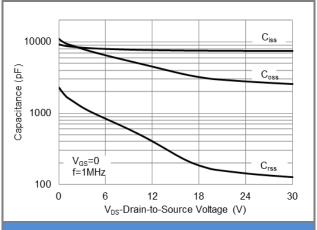




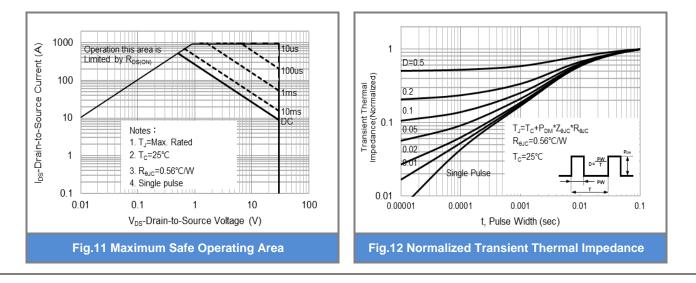












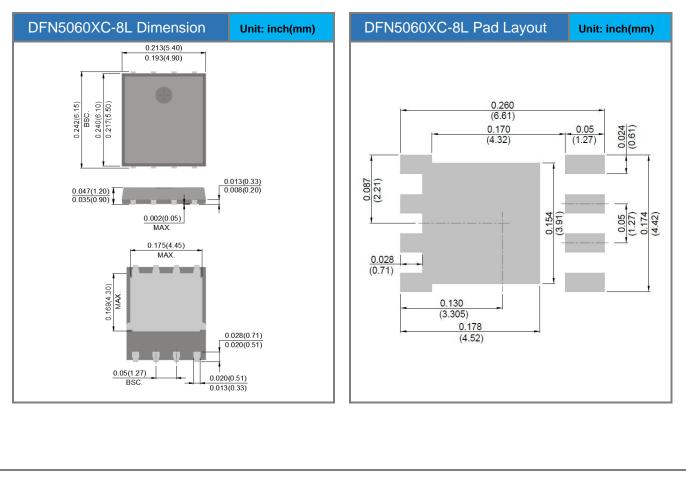


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Product and Packing Information

Part No.	Package Type	Packing Type	Marking	
PJQ5514S6C-AU	DFN5060XC-8L	3K pcs / 13" reel	5514S6C	

Packaging Information & Mounting Pad Layout





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